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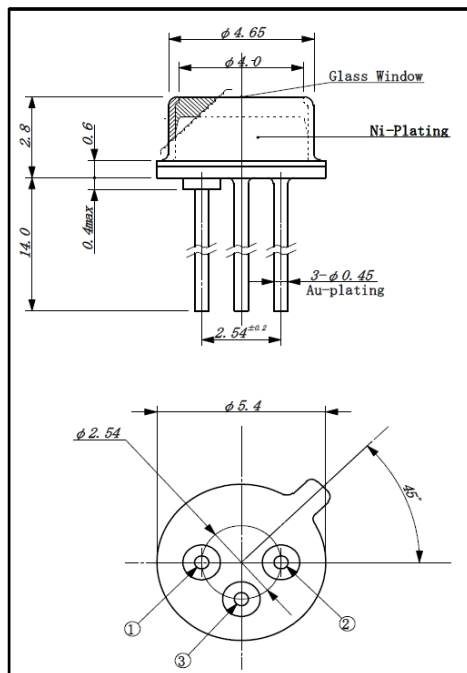
Data Sheet

Infrared photodiode

EOPD-1300-0-0.3-1

Rev. 04, 2016

Spectral range	Type	Case
Infrared	InGaAs	TO-46, glass window cap



①Case ②Cathode ③Anode

Features:

- High speed response (max. 2 Gbps)
- High reliability
- High sensitivity

Applications:

- High speed optical communications
- Optical LAN
- Optical switches
- Ethernet fiber channel

All dimensions in mm, tolerance: ± 0.2

Electro-optical characteristics:

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameters	Symbol	Min	Typ	Max	Unit	Test conditions
Active area size			$\emptyset 0.3$		mm	
Sensitivity range	λ	800		1750	nm	$V_R = 0 \text{ V}$
Dark current	I_D			1	μA	$V_R = 2 \text{ V}$
Junction capacitance	C_j		15		pF	$V_R = 0 \text{ V}$
Photocurrent @ 1300 nm	I_{PH}		30		μA	$V_R = 5 \text{ V}$, $E_e = 1 \text{ mW/cm}^2$
Breakdown voltage	V_{BR}	5			V	$I_R = 10 \mu\text{A}$

Absolute maximum ratings

Parameters	Min	Max	Unit
Operating temperature	-40	+85	$^{\circ}\text{C}$
Storage temperature	-40	+125	$^{\circ}\text{C}$

Art. No. 143 049



We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.